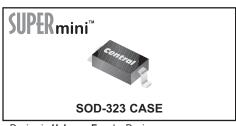


### CMDSH-3

## SURFACE MOUNT SILICON SCHOTTKY DIODE



• Device is *Halogen Free* by Design



www.centralsemi.com

## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMDSH-3 type is a silicon Schottky diode, manufactured in a SUPERmini™ surface mount package, designed for fast switching applications requiring a low forward voltage drop.

**MARKING CODE: S1** 

MAXIMUM RATINGS: (T <sub>A</sub> =25°C unless otherwise noted)	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	$V_{RRM}$	30	V
Average Forward Current	IO	100	mA
Peak Forward Surge Current, tp=10ms	I <sub>FSM</sub>	750	mA
Power Dissipation	$P_{D}$	250	mW
Power Dissipation (T <sub>L</sub> =25°C)	$P_{D}$	833	mW
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
Thermal Resistance	$\Theta_{\sf JA}$	500	°C/W
Thermal Resistance	$\Theta_{\sf JL}$	150	°C/W

ELECTRICAL SYMBOL	CHARACTERISTICS: (T <sub>A</sub> =25°C) TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_{R}$	V <sub>R</sub> =25V			1.0	μΑ
$BV_R$	I <sub>F</sub> =100μA	30			V
VF	I <sub>F</sub> =2.0mA		0.30		V
VF	I <sub>F</sub> =15mA		0.36		V
$V_{F}$	I <sub>F</sub> =50mA		0.47	0.55	V
VF	I <sub>F</sub> =100mA		0.58	0.80	V
CJ	V <sub>R</sub> =10V, f=1.0MHz		7.0		pF

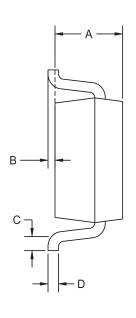


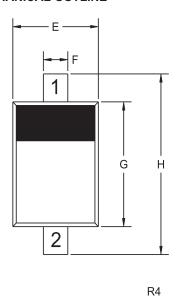
## CMDSH-3

# SURFACE MOUNT SILICON SCHOTTKY DIODE



### **SOD-323 CASE - MECHANICAL OUTLINE**





## LEAD CODE:

- 1) Cathode
- 2) Anode

#### **MARKING CODE: S1**

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.031	0.039	0.80	1.00			
В	0.000	0.004	0.00	0.10			
С	0.008	-	0.20	-			
D	0.004	0.007	0.11	0.19			
Е	0.045	0.053	1.15	1.35			
F	-	0.014	-	0.35			
G	0.063	0.071	1.60	1.80			
Н	0.094	0.102	2.40	2.60			

SOD-323 (REV: R4)

R8 (24-July 2012)